

| REVISIONS | | | | | | | | | | | | | | | | | | | | |
|-----------|--|-----------------|----------------|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|
| LTR | DESCRIPTION | DATE (YR-MO-DA) | APPROVED | | | | | | | | | | | | | | | | | |
| A | Add vendor CAGE F8859. Add device Class V criteria. Add delta limits, table III. Add case outline X. Update boilerplate to MIL-PRF-38535 requirements. – lgt | 01-05-10 | Raymond Monnin | | | | | | | | | | | | | | | | | |
| B | Update boilerplate paragraphs to the current MIL-PRF-38535 requirements. - LTG | 09-08-12 | Thomas M. Hess | | | | | | | | | | | | | | | | | |

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| REV | | | | | | | | | | | | | | | | | | | | |
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| REV | B | B | B | B | | | | | | | | | | | | | | | | |
| SHEET | 15 | 16 | 17 | 18 | | | | | | | | | | | | | | | | |

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| REV STATUS | REV | B | B | B | B | B | B | B | B | B | B | B | B | B | B | B | B | B | B |
| OF SHEETS | SHEET | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | 18 |

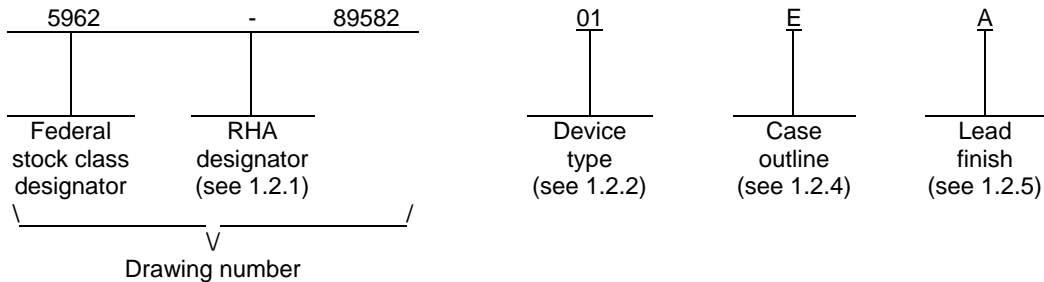
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|--|-----------------------------------|--|---|-----------|---------------------------|-------------------|---------------|--|
| PMIC N/A | PREPARED BY Monica L. Poelking | DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 http://www.dscclia.mil | | | | | | |
| STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A | CHECKED BY Raymond Monnin | | | | | | | |
| | APPROVED BY Michael A. Frye | MICROCIRCUIT, DIGITAL, ADVANCED CMOS, SYNCHRONOUS PRESETTABLE BINARY COUNTER, MONOLITHIC SILICON | | | | | | |
| | DRAWING APPROVAL DATE 89-06-05 | | | | | | | |
| | | REVISION LEVEL B | <table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 15%;">SIZE A</td> <td style="width: 25%;">CAGE CODE 67268</td> <td style="width: 60%; text-align: center;">5962-89582</td> </tr> <tr> <td colspan="3" style="text-align: center;">SHEET 1 OF 18</td> </tr> </table> | SIZE A | CAGE CODE 67268 | 5962-89582 | SHEET 1 OF 18 | |
| SIZE A | CAGE CODE 67268 | 5962-89582 | | | | | | |
| SHEET 1 OF 18 | | | | | | | | |

1. SCOPE

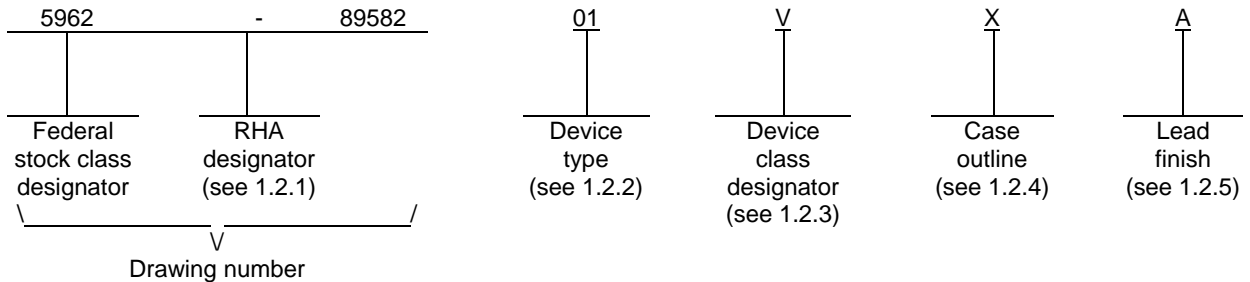
1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following examples.

For device classes M and Q:



For device class V:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

| <u>Device type</u> | <u>Generic number</u> | <u>Circuit function</u> |
|--------------------|-----------------------|--|
| 01 | 54AC163 | Synchronous presettable binary counter |

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as listed below. Since the device class designator has been added after the original issuance of this drawing, device classes M and Q designators will not be included in the PIN and will not be marked on the device.

| <u>Device class</u> | <u>Device requirements documentation</u> |
|---------------------|---|
| M | Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A |
| Q or V | Certification and qualification to MIL-PRF-38535 |

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1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

| <u>Outline letter</u> | <u>Descriptive designator</u> | <u>Terminals</u> | <u>Package style</u> |
|-----------------------|-------------------------------|------------------|------------------------------|
| E | GDIP1-T16 or CDIP2-T16 | 16 | Dual-in-line |
| F | GDFP2-F16 or CDFP3-F16 | 16 | Flat pack |
| 2 | CQCC1-N20 | 20 | Square leadless chip carrier |
| X | CDFP4-F16 | 16 | Flat pack |

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

1.3 Absolute maximum ratings. 1/ 2/ 3/

| | |
|--|----------------------------------|
| Supply voltage range (V_{CC}) | -0.5 V dc to +7.0 V dc |
| DC input voltage range (V_{IN}) | -0.5 V dc to $V_{CC} + 0.5$ V dc |
| DC output voltage range (V_{OUT}) | -0.5 V dc to $V_{CC} + 0.5$ V dc |
| Clamp diode current (I_{IK} , I_{OK}) | ± 20 mA |
| DC output current | ± 50 mA |
| DC V_{CC} or GND current (per pin) | ± 50 mA |
| Storage temperature range (T_{STG}) | -65°C to +150°C |
| Maximum power dissipation (P_D) | 500 mW |
| Lead temperature (soldering, 10 seconds) | +300°C |
| Thermal resistance, junction-to-case (θ_{JC}) | See MIL-STD-1835 |
| Junction temperature (T_J) | +175°C 4/ |

1.4 Recommended operating conditions. 2/ 3/ 5/

| | |
|---|------------------------|
| Supply voltage range (V_{CC}) | +2.0 V dc to +6.0 V dc |
| Input voltage range (V_{IN}) | +0.0 V dc to V_{CC} |
| Output voltage range (V_{OUT}) | +0.0 V dc to V_{CC} |
| Case operating temperature range (T_C) | -55°C to +125°C |
| Input rise or fall times ($\Delta V/\Delta t$): | |
| $V_{CC} = 3.6$ V | 0 to 10 ns |
| $V_{CC} = 5.5$ V | 0 to 8 ns |

- 1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 2/ Unless otherwise noted, all voltages are referenced to GND.
- 3/ The limits for the parameters specified herein shall apply over the full specified V_{CC} range and case temperature range of -55°C to +125°C.
- 4/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.
- 5/ Operation from 2.0 V dc to 3.0 V dc is provided for compatibility with data retention and battery back-up systems. Data retention implies no input transition and no stored data loss with the following conditions: $V_{IH} \geq 70\% V_{CC}$, $V_{IL} \leq 30\% V_{CC}$, $V_{OH} \geq 70\% V_{CC}$ @ -20 μ A, $V_{OL} \leq 30\% V_{CC}$ @ 20 μ A.

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2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://assist.daps.dla.mil/quicksearch/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Non-Government publications. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents cited in the solicitation or contract.

ELECTRONIC INDUSTRIES ALLIANCE (EIA)

JEDEC Standard No. 20 - Standard for Description of 54/74ACXXXXX and 54/74ACTXXXXX Advanced High-Speed CMOS Devices.

(Copies of these documents are available online at <http://www.jedec.org> or from Electronic Industries Alliance, 2500 Wilson Boulevard, Arlington, VA 22201-3834).

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.

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3.2.5 Counting sequence. The counting sequence shall be as specified on figure 4.

3.2.6 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified on figure 5.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.

3.9 Verification and review for device class M. For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 40 (see MIL-PRF-38535, appendix A).

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TABLE I. Electrical performance characteristics.

| Test and MIL-STD-883 test method <u>1/</u> | Symbol | Test conditions <u>2/</u> -55°C ≤ T _C ≤ +125°C +3.0 V ≤ V _{CC} ≤ +5.5 V unless otherwise specified | Device type and device class | V _{CC} | Group A subgroups | Limits <u>3/</u> | | Unit |
|--|------------------------------|---|------------------------------|-----------------|-------------------|------------------|------|------|
| | | | | | | Min | Max | |
| Positive input clamp voltage 3022 | V _{IC+} | For input under test I _{IN} = 1.0 mA | All V | 0.0 V | 1 | 0.4 | 1.5 | V |
| Negative input clamp voltage 3022 | V _{IC-} | For input under test I _{IN} = -1.0 mA | All V | Open | 1 | -0.4 | -1.5 | V |
| High level output voltage 3006 | V _{OH} <u>4/</u> | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OH} = -50 μA | All | 3.0 V | 1, 2, 3 | 2.9 | | V |
| | | | All | 4.5 V | | 4.4 | | |
| | | | All | 5.5 V | | 5.4 | | |
| | | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OH} = -12 mA | All | 3.0 V | 1 | 2.56 | | |
| | | | All | | 2, 3 | 2.4 | | |
| | | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OH} = -24 mA | All | 4.5 V | 1 | 3.86 | | |
| | | | All | | 2, 3 | 3.7 | | |
| | | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OH} = -50 mA | All | 5.5 V | 1 | 4.86 | | |
| | | | All | | 2, 3 | 4.7 | | |
| | | | All | 5.5 V | 1, 2, 3 | 3.85 | | |
| Low level output voltage 3007 | V _{OL} <u>4/</u> | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OL} = 50 μA | All | 3.0 V | 1, 2, 3 | | 0.1 | V |
| | | | All | 4.5 V | | | 0.1 | |
| | | | All | 5.5 V | | | 0.1 | |
| | | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OL} = 12 mA | All | 3.0 V | 1 | | 0.36 | |
| | | | All | | 2, 3 | | 0.5 | |
| | | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OL} = 24 mA | All | 4.5 V | 1 | | 0.36 | |
| | | | All | | 2, 3 | | 0.5 | |
| | | V _{IN} = V _{IH} minimum or V _{IL} maximum I _{OL} = 50 mA | All | 5.5 V | 1 | | 0.36 | |
| | | | All | | 2, 3 | | 0.5 | |
| | | | All | 5.5 V | 1, 2, 3 | | 1.65 | |
| High level input voltage | V _{IH} <u>5/</u> | | All | 3.0 V | 1, 2, 3 | 2.1 | | V |
| | | | All | 4.5 V | | 3.15 | | |
| | | | All | 5.5 V | | 3.85 | | |
| Low level input voltage | V _{IL} <u>5/</u> | | All | 3.0 V | 1, 2, 3 | | 0.9 | V |
| | | | All | 4.5 V | | | 1.35 | |
| | | | All | 5.5 V | | | 1.65 | |

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – Continued.

| Test and MIL-STD-883 test method <u>1/</u> | Symbol | Test conditions <u>2/</u> -55°C ≤ T _C ≤ +125°C +3.0 V ≤ V _{CC} ≤ +5.5 V unless otherwise specified | Device type and device class | V _{CC} | Group A subgroups | Limits <u>3/</u> | | Unit | |
|---|--------------------------------|---|------------------------------|-----------------|-------------------|------------------|------|------|--|
| | | | | | | Min | Max | | |
| Input leakage current low 3009 | I _{IL} | V _{IN} = 0.0 V | All All | 5.5 V | 1 | | -0.1 | μA | |
| | | | | | 2, 3 | | -1.0 | | |
| Input leakage current high 3010 | I _{IH} | V _{IN} = 5.5 V | All All | 5.5 V | 1 | | 0.1 | μA | |
| | | | | | 2, 3 | | 1.0 | | |
| Quiescent supply current, output high 3005 | I _{CCH} | V _{IN} = V _{CC} or GND I _o = 0 A | All All | 5.5 V | 1 | | 4 | μA | |
| | | | | | 2, 3 | | 80 | | |
| Quiescent supply current, output low 3005 | I _{CCL} | V _{IN} = V _{CC} or GND I _o = 0 A | All All | 5.5 V | 1 | | 4 | μA | |
| | | | | | 2, 3 | | 80 | | |
| Input capacitance 3012 | C _{IN} | See 4.4.1c T _C = +25°C | All All | 5.0 V | 4 | | 8.0 | pF | |
| Power dissipation capacitance | C _{PD} <u>6/</u> | See 4.4.1c T _C = +25°C, f = 1 MHz | All All | 5.0 V | 4 | | 60.0 | pF | |
| Functional tests 3014 | <u>7/</u> | See 4.4.1b V _{IN} = V _{IH} or V _{IL} Verify output V _{OUT} | All All | 3.0 V | 7, 8 | L | H | | |
| | | | | 5.5 V | 7, 8 | L | H | | |
| Propagation delay time, high to low low to high, CP to Qn (Count mode) 3003 | t _{PHL1} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 1.0 | 10.5 | ns | |
| | | | All All | 4.5 V | | 1.0 | 8.0 | | |
| | t _{PLH1} <u>8/</u> | | All All | 3.0 V | | 1.0 | 11.0 | | |
| | t _{PLH1} <u>8/</u> | | All All | 4.5 V | | 1.0 | 8.0 | | |
| | t _{PHL1} <u>8/</u> | T _C = -55°C and +125°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 10, 11 | 1.0 | 12.5 | ns | |
| | | | All All | 4.5 V | | 1.0 | 9.5 | | |
| | t _{PLH1} <u>8/</u> | | All All | 3.0 V | | 1.0 | 13.5 | | |
| | t _{PLH1} <u>8/</u> | | All All | 4.5 V | | 1.0 | 9.5 | | |

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – Continued.

| Test and MIL-STD-883 test method <u>1/</u> | Symbol | Test conditions <u>2/</u> -55°C ≤ T _C ≤ +125°C +3.0 V ≤ V _{CC} ≤ +5.5 V unless otherwise specified | Device type and device class | V _{CC} | Group A subgroups | Limits <u>3/</u> | | Unit | |
|--|--|---|---|-----------------|-------------------|------------------|------|------|----|
| | | | | | | Min | Max | | |
| Propagation delay time, high to low low to high, CP to Qn (Load mode) 3003 | t _{PHL2} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 1.0 | 9.5 | ns | |
| | | | All All | 4.5 V | | 1.0 | 7.0 | | |
| | | | All All | 3.0 V | | 1.0 | 10.5 | | |
| | | | All All | 4.5 V | | 1.0 | 7.5 | | |
| | t _{PLH2} <u>8/</u> | T _C = -55°C and +125°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 10, 11 | 1.0 | 12.0 | ns | |
| | | | All All | 4.5 V | | 1.0 | 8.5 | | |
| | | | All All | 3.0 V | | 1.0 | 12.5 | | |
| | | | All All | 4.5 V | | 1.0 | 9.0 | | |
| | Propagation delay time, high to low low to high, CP to TC 3003 | t _{PHL3} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 1.0 | 12.5 | ns |
| | | | | All All | 4.5 V | | 1.0 | 10.0 | |
| | | | | All All | 3.0 V | | 1.0 | 13.5 | |
| | | | | All All | 4.5 V | | 1.0 | 9.5 | |
| t _{PLH3} <u>8/</u> | | T _C = -55°C and +125°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 10, 11 | 1.0 | 15.0 | ns | |
| | | | All All | 4.5 V | | 1.0 | 11.0 | | |
| | | | All All | 3.0 V | | 1.0 | 16.5 | | |
| | | | All All | 4.5 V | | 1.0 | 11.0 | | |
| Propagation delay time, high to low low to high, CET to TC 3003 | | t _{PHL4} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 1.0 | 10.5 | ns |
| | | | | All All | 4.5 V | | 1.0 | 7.5 | |
| | | | | All All | 3.0 V | | 1.0 | 9.0 | |
| | | | | All All | 4.5 V | | 1.0 | 6.0 | |
| | t _{PLH4} <u>8/</u> | T _C = -55°C and +125°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 10, 11 | 1.0 | 12.0 | ns | |
| | | | All All | 4.5 V | | 1.0 | 9.0 | | |
| | | | All All | 3.0 V | | 1.0 | 11.0 | | |
| | | | All All | 4.5 V | | 1.0 | 7.5 | | |

See footnotes at end of table.

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TABLE I. Electrical performance characteristics – Continued.

| Test and MIL-STD-883 test method <u>1/</u> | Symbol | Test conditions <u>2/</u> -55°C ≤ T _C ≤ +125°C +3.0 V ≤ V _{CC} ≤ +5.5 V unless otherwise specified | Device type and device class | V _{CC} | Group A subgroups | Limits <u>3/</u> | | Unit |
|---|------------------------------|---|------------------------------|-----------------|-------------------|------------------|-----|------|
| | | | | | | Min | Max | |
| Set-up time, high or low, $\overline{\text{SR}}$ to CP 3003 | t _{s1} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 14.0 | | ns |
| | | | All All | 4.5 V | | 9.5 | | |
| | | | All All | 3.0 V | 10, 11 | 17.0 | | |
| | | | All All | 4.5 V | | 12.0 | | |
| Hold time, high or low, $\overline{\text{SR}}$ to CP 3003 | t _{h1} <u>8/</u> | T _C = -55°C and +125°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | -1.0 | | ns |
| | | | | | 10, 11 | -0.5 | | |
| | | | All All | 4.5 V | 9, 10, 11 | 0.0 | | |
| Set-up time, high or low, P _n to CP 3003 | t _{s2} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 13.5 | | ns |
| | | | All All | 4.5 V | | 8.5 | | |
| | | | All All | 3.0 V | 10, 11 | 17.0 | | |
| | | | All All | 4.5 V | | 11.0 | | |
| Hold time, high or low, P _n to CP 3003 | t _{h2} <u>8/</u> | T _C = -55°C and +125°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | -1.0 | | ns |
| | | | | | 10, 11 | -0.5 | | |
| | | | All All | 4.5 V | 9, 10, 11 | 0.0 | | |
| Set-up time, high or low, $\overline{\text{PE}}$ to CP 3003 | t _{s3} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 12.5 | | ns |
| | | | All All | 4.5 V | | 8.0 | | |
| | | | All All | 3.0 V | 10, 11 | 16.0 | | |
| | | | All All | 4.5 V | | 9.5 | | |
| Hold time, high or low, $\overline{\text{PE}}$ to CP 3003 | t _{h3} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | -1.5 | | ns |
| | | | All All | 4.5 V | | -0.5 | | |
| | | | All All | 3.0 V | 10, 11 | -0.5 | | |
| | | | All All | 4.5 V | | 0 | | |
| Set-up time, high or low, CEP or CET to CP 3003 | t _{s4} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 6.5 | | ns |
| | | | All All | 4.5 V | | 4.5 | | |
| | | | All All | 3.0 V | 10, 11 | 8.0 | | |
| | | | All All | 4.5 V | | 5.5 | | |

See footnotes at end of table.

**STANDARD
MICROCIRCUIT DRAWING**
DEFENSE SUPPLY CENTER COLUMBUS
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
B

5962-89582

SHEET
9

TABLE I. Electrical performance characteristics - Continued.

| Test and MIL-STD-883 test method <u>1/</u> | Symbol | Test conditions <u>2/</u> -55°C ≤ T _C ≤ +125°C +3.0 V ≤ V _{CC} ≤ +5.5 V unless otherwise specified | Device type and device class | V _{CC} | Group A subgroups | Limits <u>3/</u> | | Unit |
|---|-------------------------------|---|------------------------------|-----------------|-------------------|------------------|-----|------|
| | | | | | | Min | Max | |
| Hold time, high or low, CEP or CET to CP 3003 | t _{h4} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9, 10, 11 | 0 | | ns |
| | | | All All | 4.5 V | 9 | 0 | | |
| | | | All All | 4.5 V | 10, 11 | 0.5 | | |
| Clock pulse width, CP (Count mode) 3003 | t _{w1} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9, 10, 11 | 5.0 | | ns |
| | | | All All | 4.5 V | 9, 10, 11 | 5.0 | | |
| Clock pulse width, CP (Load mode) 3003 | t _{w2} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9, 10, 11 | 5.0 | | ns |
| | | | All All | 4.5 V | 9, 10, 11 | 5.0 | | |
| Maximum clock frequency, CP 3003 | f _{max} <u>8/</u> | T _C = +25°C C _L = 50 pF minimum R _L = 500Ω See figure 5 | All All | 3.0 V | 9 | 70 | | MHz |
| | | | All All | 4.5 V | | 95 | | |
| | | | All All | 3.0 V | 10, 11 | 55 | | |
| | | | All All | 4.5 V | | 90 | | |

1/ For tests not listed in the referenced MIL-STD-883, [e.g. V_{IH}, V_{IL}], utilize the general test procedure under the conditions listed herein.

2/ Each input/output, as applicable, shall be tested at the specified temperature, for the specified limits, to the tests in table I herein. Output terminals not designated shall be high level logic, low level logic, or open, except as follows:

- V_{IC} (pos) tests, the GND terminal can be open. T_C = +25°C.
- V_{IC} (neg) tests, the V_{CC} terminal shall be open. T_C = +25°C.
- All I_{CC} tests, the output terminal shall be open. When performing these tests, the current meter shall be placed in the circuit such that all current flows through the meter.

Additional detailed information on qualified devices (i.e. pin for pin conditions and testing sequence) is available from the qualifying activity (DSCC-VQC) upon request.

3/ For negative and positive voltage and current values, the sign designates the potential difference in reference to GND and the direction of current flow, respectively; and the absolute value of the magnitude, not the sign, is relative to the minimum and maximum limits, as applicable, listed herein. All devices shall meet or exceed the limits specified in table I, as applicable, at 3.0 V ≤ V_{CC} ≤ 3.6 V and 4.5 V ≤ V_{CC} ≤ 5.5 V.

4/ The V_{OH} and V_{OL} tests shall be tested at V_{CC} = 3.0 V and 4.5 V. The V_{OH} and V_{OL} tests are guaranteed, if not tested, for other values of V_{CC}. Limits shown apply to operation at V_{CC} = 3.3 V ± 0.3 V and V_{CC} = 5.0 V ± 0.5 V. Tests with input current at +50 mA or -50 mA are performed on only one input at a time with duration not to exceed 10 ms. Transmission driving tests may be performed using V_{IN} = V_{CC} or GND. When V_{IN} = V_{CC} or GND is used, the test is guaranteed for V_{IN} = V_{IH} minimum and V_{IL} maximum.

5/ The V_{IH} and V_{IL} tests are not required if applied as forcing functions for V_{OH} and V_{OL} tests.

| | | | |
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TABLE I. Electrical performance characteristics - Continued.

- 6/ Power dissipation capacitance (C_{PD}) determines both the power consumption (P_D) and dynamic current consumption (I_S).
Where:

$$P_D = (C_{PD} + C_L) (V_{CC} \times V_{CC})f + (I_{CC} \times V_{CC})$$

$$I_S = (C_{PD} + C_L) V_{CC}f + I_{CC}$$
 f is the frequency of the input signal and C_L is the external output load capacitance.
- 7/ Tests shall be performed in sequence, attributes data only. Functional tests shall include the truth table and other logic patterns used for fault detection. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2 herein. Functional tests shall be performed in sequence as approved by the qualifying activity on qualified devices. For V_{OUT} measurements, $L \leq 0.3V_{CC}$ and $H \geq 0.7V_{CC}$.
- 8/ For propagation delay tests, all paths must be tested. AC limits at $V_{CC} = 5.5$ V are equal to the limits at $V_{CC} = 4.5$ V and guaranteed by testing at $V_{CC} = 4.5$ V. AC limits at $V_{CC} = 3.6$ V are equal to limits at $V_{CC} = 3.0$ V and guaranteed by testing at $V_{CC} = 3.0$ V. Minimum ac limits for $V_{CC} = 5.5$ V are 1.0 ns and guaranteed by guardbanding the $V_{CC} = 4.5$ V minimum limits to 1.5 ns.

| Case outlines | E, F, and X | 2 |
|-----------------|-----------------|-----------------|
| Terminal number | Terminal symbol | |
| 1 | \overline{SR} | NC |
| 2 | CP | \overline{SR} |
| 3 | P0 | CP |
| 4 | P1 | P0 |
| 5 | P2 | P1 |
| 6 | P3 | NC |
| 7 | CEP | P2 |
| 8 | GND | P3 |
| 9 | PE | CEP |
| 10 | CET | GND |
| 11 | Q3 | NC |
| 12 | Q2 | PE |
| 13 | Q1 | CET |
| 14 | Q0 | Q3 |
| 15 | TC | Q2 |
| 16 | V_{CC} | NC |
| 17 | ----- | Q1 |
| 18 | ----- | Q0 |
| 19 | ----- | TC |
| 20 | ----- | V_{CC} |

NC = No connection

FIGURE 1. Terminal connections.

| | | | |
|---|-------------------------|-----------------------------------|---------------------------|
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| Inputs | | | | Action on the rising clock edge |
|------------------------|------------------------|-----|-----|---------------------------------|
| $\overline{\text{SR}}$ | $\overline{\text{PE}}$ | CET | CEP | |
| L | X | X | X | Reset (clear) |
| H | L | X | X | Load (Pn to Qn) |
| H | H | H | H | Count (increment) |
| H | H | L | | No change (hold) |
| H | H | X | L | No change (hold) |

H = High voltage level
L = Low voltage level
X = Irrelevant

FIGURE 2. Truth table.

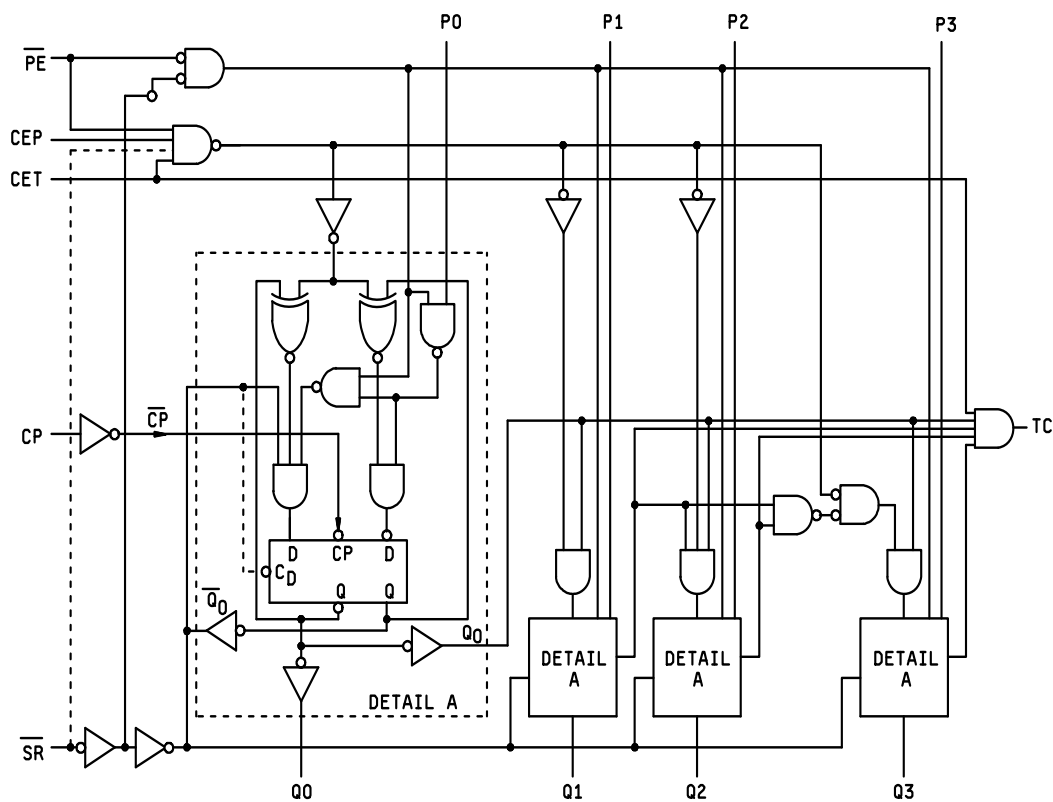
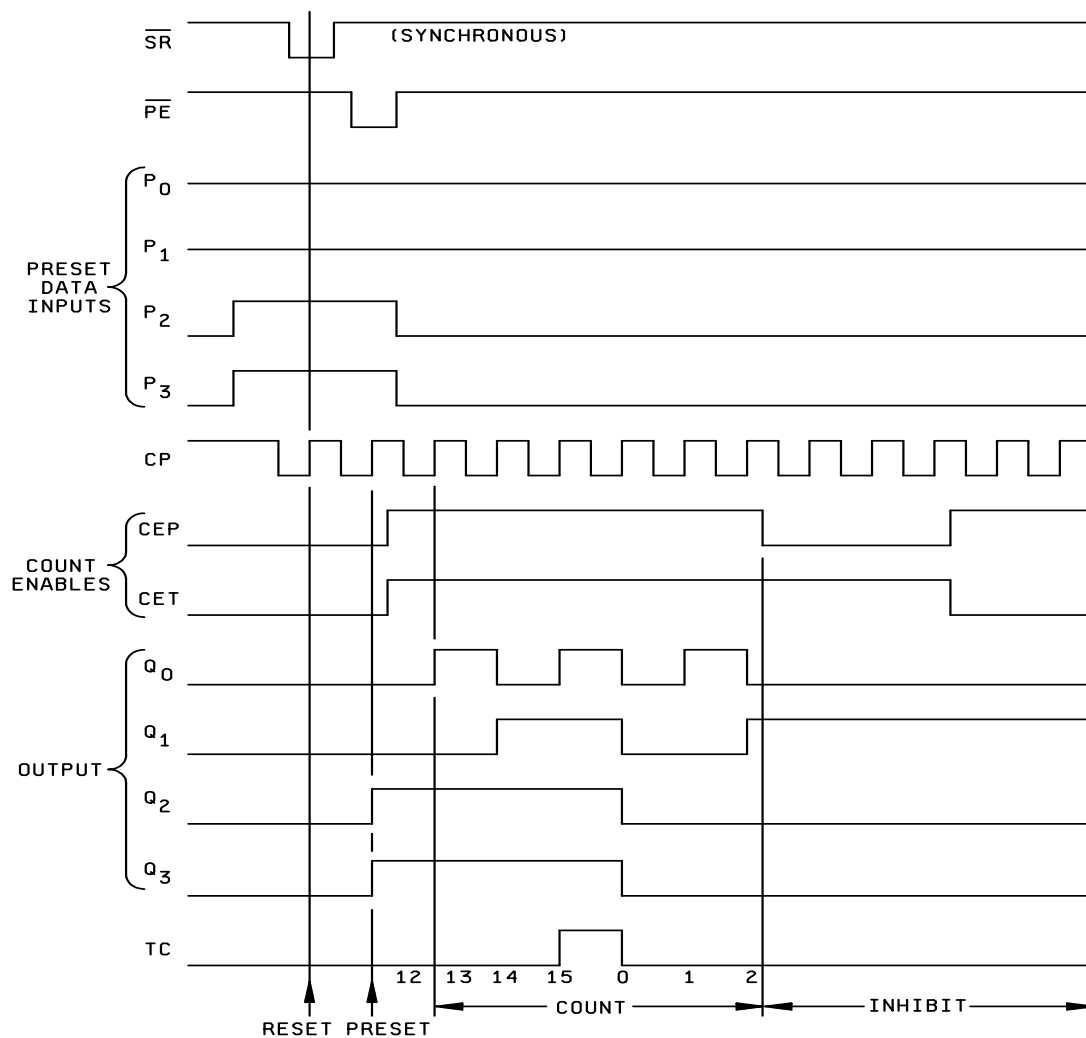


FIGURE 3. Logic diagram.

| | | | |
|---|-------------------|----------------------------|--------------------|
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Sequence illustrated in waveform:

1. Reset outputs to zero.
2. Preset to binary twelve.
3. Count to thirteen, fourteen, fifteen, zero, one, and two.
4. Inhibit.

FIGURE 4. Counting sequence.

| | | | |
|---|------------------|----------------------------|--------------------|
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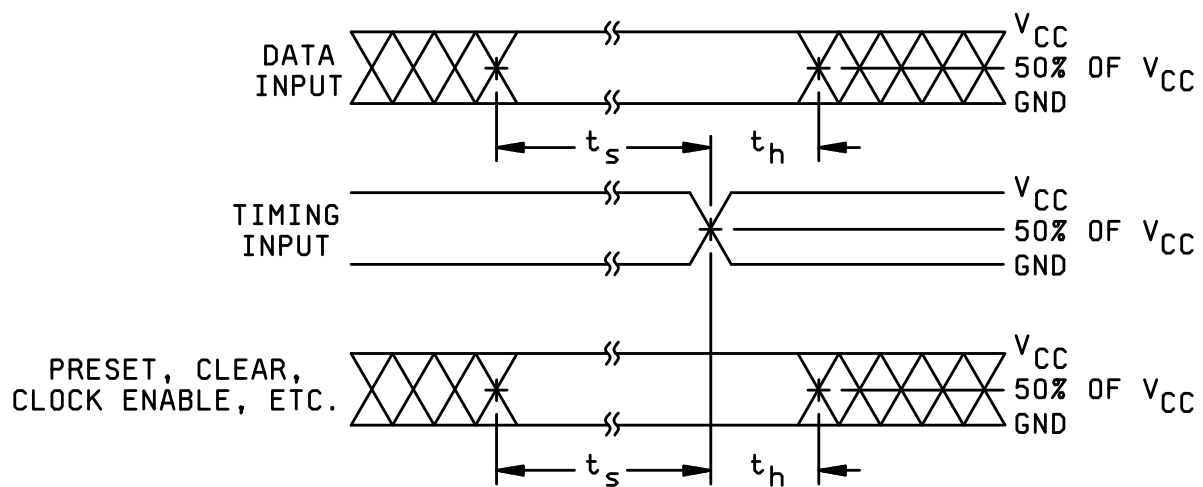
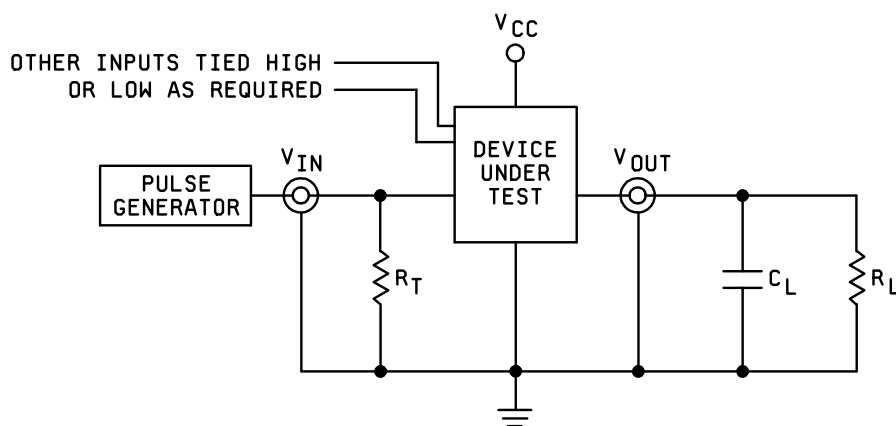
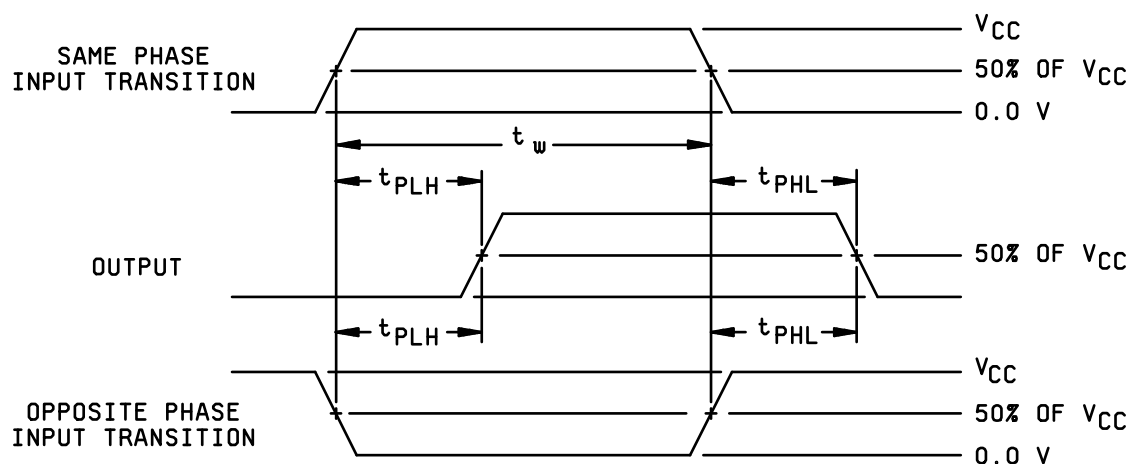


FIGURE 5. Switching waveforms and test circuit.

| | | | |
|---|------------------|----------------------------|--------------------|
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NOTES:

1. $C_L = 50$ pF or equivalent (includes probe and jig capacitance).
2. R_T should be equal to Z_{OUT} of the pulse generator.
3. $R_L = 500\Omega$ or equivalent.
4. Input signal from pulse generator: $V_{IN} = 0.0$ V to V_{CC} ; $PRR \leq 1$ MHz; $Z_O = 50\Omega$; $t_r \leq 3.0$ ns; $t_f \leq 3.0$ ns; t_r and t_f shall be measured from 10% of V_{CC} to 90% of V_{CC} and from 90% of V_{CC} to 10% of V_{CC} , respectively; duty cycle = 50 percent.
5. Timing parameters shall be tested at a minimum input frequency of 1MHz.
6. The outputs are measured one at a time with one transition per measurement.

FIGURE 5. Switching waveforms and test circuit – Continued.

| | | | |
|---|------------------|----------------------------|--------------------|
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4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.
 - (2) $T_A = +125^{\circ}\text{C}$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table in figure 2 herein. The test vectors used to verify the truth table shall, at a minimum, test all functions of each input and output. All possible input to output logic patterns per function shall be guaranteed, if not tested, to the truth table in figure 2, herein. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.
- c. C_{IN} and C_{PD} shall be measured only for initial qualification and after process or design changes which may affect capacitance. C_{IN} shall be measured between the designated terminal and GND at a frequency of 1 MHz. C_{PD} shall be tested in accordance with the latest revision of JEDEC Standard No. 20 and table I herein. For C_{IN} and C_{PD} , test all applicable pins on five devices with zero failures.

| | | | |
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TABLE II. Electrical test requirements.

| Test requirements | Subgroups (in accordance with MIL-STD-883, method 5005, table I) | Subgroups (in accordance with MIL-PRF-38535, table III) | |
|--|---|---|---|
| | Device class M | Device class Q | Device class V |
| Interim electrical parameters (see 4.2) | --- | --- | 1 |
| Final electrical parameters (see 4.2) | <u>1/</u> 1, 2, 3, 7, 8, 9 | <u>1/</u> 1, 2, 3, 7, 8, 9 | <u>2/</u> , <u>3/</u> 1, 2, 3, 7, 8, 9 |
| Group A test requirements (see 4.4) | 1, 2, 3, 4, 7, 8, 9, 10, 11 | 1, 2, 3, 4, 7, 8, 9, 10, 11 | 1, 2, 3, 4, 7, 8, 9, 10, 11 |
| Group C end-point electrical parameters (see 4.4) | 1, 2, 3 | 1, 2, 3 | <u>3/</u> 1, 2, 3, 7, 8, 9, 10, 11 |
| Group D end-point electrical parameters (see 4.4) | 1, 2, 3 | 1, 2, 3 | 1, 2, 3 |
| Group E end-point electrical parameters (see 4.4) | 1, 7, 9 | 1, 7, 9 | 1, 7, 9 |

1/ PDA applies to subgroup 1.

2/ PDA applies to subgroups 1, 7 and deltas.

3/ Delta limits as specified in table III, shall be required where specified, and the delta limits shall be completed with reference to the zero hour electrical parameters.

TABLE III. Burn-in and operating life test, delta parameters (+25°C).

| Parameter | Symbol | Delta limits |
|--|----------|--------------|
| Quiescent current | I_{CC} | ± 300 nA |
| Input current low level | I_{IL} | ± 20 nA |
| Input current high level | I_{IH} | ± 20 nA |
| Output voltage low level $V_{CC} = 5.5$ V $I_{OL} = 24$ mA | V_{OL} | ± 0.04 V |
| Output voltage high level $V_{CC} = 5.5$ V $I_{OH} = -24$ mA | V_{OH} | ± 0.2 V |

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
- $T_A = +125^\circ\text{C}$, minimum.
- Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

| | | | |
|---|------------------|----------------------------|--------------------|
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4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$, after exposure, to the subgroups specified in table II herein.

4.5 Methods of inspection. Methods of inspection shall be specified as follows:

4.5.1 Voltage and current. Unless otherwise specified, all voltages given are referenced to the microcircuit GND terminal. Currents given are conventional current and positive when flowing into the referenced terminal.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.4 Comments. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.

6.6.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

| | | | |
|---|-----------|---------------------|-------------|
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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 09-08-12

Approved sources of supply for SMD 5962-89582 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at <http://www.dscclia.mil/Programs/Smcr/>.

| Standard microcircuit drawing PIN 1/ | Vendor CAGE number | Vendor similar PIN 2/ |
|---|--------------------------|-----------------------------|
| 5962-8958201EA | 0C7V7 | 54AC163DMQB |
| 5962-8958201FA | 0C7V7 | 54AC163FMQB |
| 5962-89582012A | 0C7V7 | 54AC163LMQB |
| 5962-8958201XA | <u>3/</u> | 54AC163K02Q |
| 5962-8958201VXA | <u>3/</u> | 54AC163K02V |
| 5962-8958201XC | <u>3/</u> | 54AC163K01Q |
| 5962-8958201VXC | <u>3/</u> | 54AC163K01V |

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

Vendor CAGE
number

0C7V7

Vendor name
and address

QP Semiconductor
2945 Oakmead Village Court
Santa Clara, CA 95051

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.